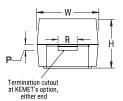


T495D226M020ATA200

General Information

T495 Auto, Tantalum, MnO2 Tantalum, Commercial Grade, 22 uF, 20%, 20 VDC, SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200, 200 mOhms, 7343, 3.1 mm, 1.3 mm

CATHODE (-) END VIEW



ANODE (+) END VIEW

Dimensions

L

W

н

т s

F

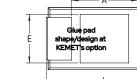
А

В

E G

Ρ

SIDE VIEW



7.3mm +/-0.3mm

4.3mm +/-0.3mm 2.8mm +/-0.3mm

1.3mm +/-0.3mm

2.4mm +/-0.1mm

0.5mm +/-0.15mm

0.13mm REF

3.6mm MIN

3.5mm REF

3.5mm REF

0.9mm REF

Click here for the 3D model.

Series	T495 Auto
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200
Features	Low ESR, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	446.84 mg

Specifications	
Capacitance	22 uF
Tolerance	20%
Voltage DC	20 VDC (85C), 13.4 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	4% 120Hz 25C
Failure Rate	N/A
ESR	200 mOhms (100kHz 25C)
Ripple Current	870 mA (rms, 100kHz 25C), 783 mA (rms, 85C), 348 mA (rms, 125C)
Leakage Current	4.4 uA (5min 25°C)

R	1mm REF
x	0.1mm +/-0.1mm REF
Packaging Specifications	
Packaging	T&R, 178mm

500

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Packaging Quantity